

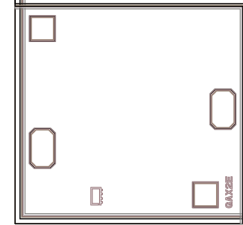
Low Noise, Wideband, Low Current Monolithic Amplifier Die

PMA2-123LN5-D+

50Ω 0.5 to 12 GHz

The Big Deal

- Ultra wideband, 0.5 to 12 GHz
- Excellent noise figure, 1.8 dB at 12 GHz
- Low Current, 30mA



Product Overview

The PMA2-123LN5-D+ is a E-PHEMT based wideband, low noise MMIC amplifier die with a unique combination of low noise, high IP3, and low current making it ideal for sensitive, high-dynamic-range receiver applications. This design operates on a single 5V supply, is well matched for 50Ω.

Key Features

Feature	Advantages
Excellent Noise Figure up to 18 GHz <ul style="list-style-type: none">• 1.8 dB typ. at 12GHz• 2.4 dB typ. at 18 GHz	Enables lower system noise figure performance.
High IP3 <ul style="list-style-type: none">• +23.4 dBm at 0.5 GHz• +24.1 dBm at 12 GHz	Combination of low noise figure and high IP3 makes this MMIC amplifier ideal for use in low noise receiver front end (RFE) as it gives the user advantages of sensitivity and two-tone IM performance at both ends of the dynamic range.
Low operating voltage & current 5V & 30mA	Low voltage & current consumption is ideal for use in amplifier chain.
Unpackaged die	Enables user to integrate it directly into hybrids.

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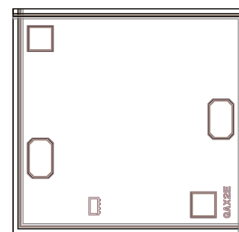
50Ω 0.5 to 12 GHz

Product Features

- Ultra wideband, 0.5 to 12 GHz
- Excellent Noise figure, 1.8 dB at 12 GHz
- Low current, 30mA
- Usable to 18 GHz

Typical Applications

- WiFi
- WLAN
- UMTS
- LTE
- WiMAX
- S-band Radar
- C-band Satcom



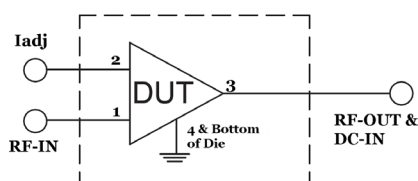
+RoHS Compliant
The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

Ordering Information: Refer to Last Page

General Description

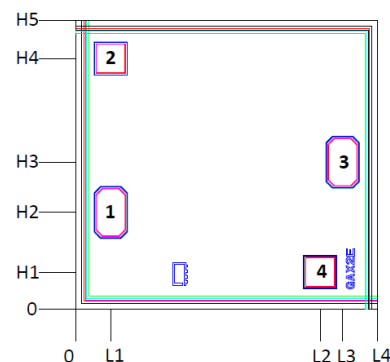
The PMA2-123LN5-D+ is a E-PHEMT based wideband, low noise MMIC amplifier die with a unique combination of low noise, high IP3, and low current making it ideal for sensitive, high-dynamic-range receiver applications. This design operates on a single 5V supply, is well matched for 50Ω.

Simplified Schematic and Pad description



Pad#	Function
1	RF-IN
2	Iadj Pin (Current Adjust)
3	RF OUT and DC-IN
4	Ground

Bonding Pad Position



Dimensions in μm, Typical

L1	L2	L3	L4	H1	H2	H3	H4	H5	Thickness	Die size	Pad size 1 & 3	Pad size 2 & 4
85	594	648	733	90	235	357	608	701	100	733 x 701	81 x 126	81 x 81

Electrical Specifications¹ at 25°C, unless noted

Parameter	Condition (GHz)	V _{DD} =5.0			Units
		Min.	Typ.	Max.	
Frequency Range		0.5		12	GHz
Noise Figure	0.5		1.4		dB
	5		1.2		
	10		1.6		
	12		1.8		
	18		2.4		
Gain	0.5		17.7		dB
	5		15.1		
	10		11.6		
	12		10.7		
	18		7.6		
Reverse Isolation	10	—	24.4	—	dB
Input Return Loss	0.5		6		dB
	5		10		
	10		10		
	12		10		
	18		7		
Output Return Loss	0.5		12		dB
	5		17		
	10		12		
	12		11		
	18		6		
Output Power at 1dB Compression ²	0.5		12.3		dBm
	5		12.2		
	10		11.6		
	12		11.5		
	18		9.6		
Output IP3	0.5		24.0		dBm
	5		23.4		
	10		23.5		
	12		24.1		
	18		21.6		
Device Operating Voltage (V _{DD})			5		V
Device Operating Current (I _{DD})		—	30	47	mA
Device Current Variation vs. Temperature ²			7.69		μA/°C
Device Current Variation vs. Voltage			0.008		mA/mV
Thermal Resistance, junction-to-junction			69.8		°C/W

1. Measured on Mini-Circuits Characterization test board with tested board loss being deducted. Die is packaged in 2X2 mm, 8-lead MCL package and soldered on TB-PMA2-123LN5+. See Characterization Test Circuit (Fig. 1)
 2. (Current at 85°C - Current at -45°C)/130

Absolute Maximum Ratings^{1,3}

Parameter	Ratings
Operating Temperature (ground lead)	-40°C to 85°C
Junction Temperature	131°C
Total Power Dissipation	0.65W
Input Power (CW), Vd=5V	+24 dBm (5 minutes max.) +7 dBm (continuous)
DC Voltage	7V

3. Permanent damage may occur if any of these limits are exceeded.
 Electrical maximum ratings are not intended for continuous normal operation.



Characterization Test Circuit

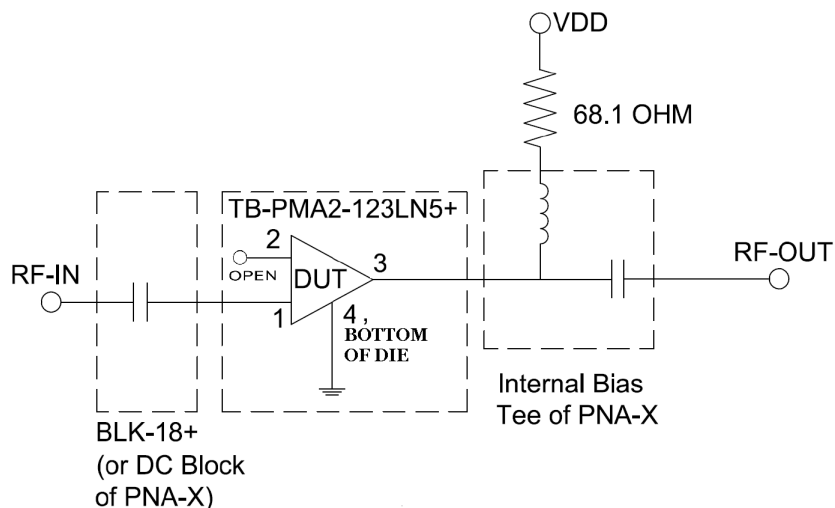


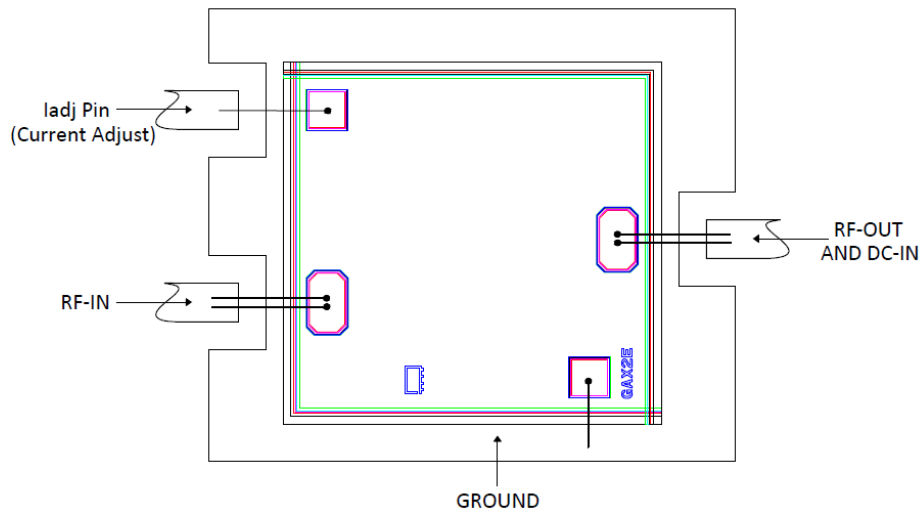
Fig 1. Application and Characterization Circuit

Note: This block diagram is used for characterization. (Die is packaged in 2x2mm, 8-lead MCLP package and soldered on Mini-Circuits Characterization test board TB-PMA2-123LN5+) Gain, Return loss, Output power at 1dB compression (P1dB), output IP3 (OIP3) and noise figure measured using Agilent's N5242A PNA-X microwave network analyzer.

Conditions:

1. Gain and Return loss: Pin= -25dBm
2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, -5 dBm/tone at output.

Assembly Diagram



Assembly and Handling Procedure

1. Storage
Dice should be stored in a dry nitrogen purged desiccators or equivalent.
2. ESD
MMIC E-PHEMT amplifier dice are susceptible to electrostatic and mechanical damage. Dice are supplied in antistatic protected material, which should be opened in clean room conditions at an appropriately grounded anti-static workstation. Devices need careful handling using correctly designed collets, vacuum pickup tips or sharp antistatic tweezers to deter ESD damage to dice.
3. Die Attach
The die mounting surface must be clean and flat. Using conductive silver filled epoxy, recommended epoxies are DieMat DM6030HK-PT/H579 or Ablestik 84-1LMISR4. Apply sufficient epoxy to meet required epoxy bond line thickness, epoxy fillet height and epoxy coverage around total die periphery. Parts shall be cured in a nitrogen filled atmosphere per manufacturer's cure condition. It is recommended to use antistatic die pick up tools only.
4. Wire Bonding
Bond pad openings in the surface passivation above the bond pads are provided to allow wire bonding to the dice gold bond pads. Thermosonic bonding is used with minimized ultrasonic content. Bond force, time, ultrasonic power and temperature are all critical parameters. Suggested wire is pure gold, 1 mil diameter. Bonds must be made from the bond pads on the die to the package or substrate. All bond wires should be kept as short as low as reasonable to minimize performance degradation due to undesirable series inductance.

Additional Detailed Technical Information <i>additional information is available on our dash board.</i>	
Performance Data	Data Table
	Swept Graphs
	S-Parameter (S2P Files) Data Set with and without port extension(.zip file)
Case Style	Die
Die Ordering and packaging information	Quantity, Package Model No.
	Small, Gel - Pak: 5,10,50,100 KGD* PMA2-123LN5-DG+ Medium†, Partial wafer: KGD*<2162 PMA2-123LN5-DP+ Large†, Full Wafer PMA2-123LN5-DF+
	†Available upon request contact sales representative
	Refer to AN-60-067
Environmental Ratings	ENV80

*Known Good Dice ("KGD") means that the dice in question have been subjected to Mini-Circuits DC test performance criteria and measurement instructions and that the parametric data of such dice fall within a predefined range. While DC testing is not definitive, it does help to provide a higher degree of confidence that dice are capable of meeting typical RF electrical parameters specified by Mini-Circuits.

ESD Rating**

Human Body Model (HBM): Class 1A (250 to <500V) in accordance with ANSI/ESD STM 5.1 - 2001

** Tested in industry standard MCLP 2x2 mm, 8-lead package.

Additional Notes

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
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